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18NT751

Seventh Semester B.E. Degree Examination, Feb./Mar. 2022 **Applications of Nanotechnology in Electronics**

Time: 3 hrs.

Max. Marks: 100

| | N | ote: Answer any FIVE full questions, choosing ONE full question from each mod | dule. | | | | |
|------|---|--|--------------------------|--|--|--|--|
| | | Module-1 | | | | | |
| 1 | a. Explain applications of nanotechnology for electric power. | | | | | | |
| | b. | Write a note on applications of nanotechnology in energy transformation. | (10 Marks) (10 Marks) | | | | |
| × | υ. | With a note on approximation | 2 | | | | |
| | | OR | | | | | |
| 2 | a. | With neat sketch explain high temperature ceramic oxide cells. | (10 Marks) | | | | |
| _ | b. | Write a note on carbon nanotubes wires and cables mention applications. | (10 Marks) | | | | |
| | | | | | | | |
| | | Module-2 | | | | | |
| 3 | a. | Explain about nanostructured thermoelectric materials. | (10 Marks) | | | | |
| | b. | Describe the energy consumption in information and communication technology. | (10 Marks) | | | | |
| | | | | | | | |
| | | OR | | | | | |
| 4 | a. | Explain about impact of nanotechnology on telecommunications. | (10 Marks) | | | | |
| | b. | With a neat sketch explain quantum cellular automata. | (10 Marks) | | | | |
| | | | 5 (8) | | | | |
| | | Module-3 | 24034 V.) | | | | |
| 5 | a. | With a neat sketch, explain biosensor. Mention applications. | (10 Marks) | | | | |
| | b. | Give a detailed note on thermal energy sensors. | (10 Marks) | | | | |
| | | | | | | | |
| | | OR | (10 Marks) | | | | |
| 6 | a. | Explain about electrical resistance sensor and electrical power sensor. | (10 Marks) (10 Marks) | | | | |
| | b. | With the sketch, explain electromagnetic sensor. | (10 Marks) | | | | |
| | | Modulo 4 | | | | | |
| ping | | Give a short note on nanomachining MEMs based on EBL. | (10 Marks) | | | | |
| 7 | a. | Explain MEMs fabrication with a neat sketch. | (10 Marks) | | | | |
| | b. | Explain Militials labrication with a near sketch, | , | | | | |
| | | OR | | | | | |
| 8 | a. | Write a note on focused ion beam wet chemical etching with the neat sketch. | (10 Marks) | | | | |
| G | b. | Give a note on large integration, future challenges and applications of MEMs. | (10 Marks) | | | | |
| | υ. | Give a note of arge megraners, | | | | | |
| | | Module-5 | | | | | |
| 9 | a. | With neat sketch explain quantum dot FETs. | (10 Marks) | | | | |
| ٠ | b. | With a neat sketch Graphene FETs. | (10 Marks) | | | | |
| | ٠. | | | | | | |
| | | OR | | | | | |
| 10 | a. | With the neat sketch explain PinFETs. | (10 Marks) | | | | |
| | | The state of the s | (10 Marks) | | | | |

Describe about the design of inverter using CNTFET.

(10 Marks)

Important Note: 1. On completing your answers, compulsorily draw diagonal cross lines on the remaining blank pages.

2. Any revealing of identification, appeal to evaluator and /or equations written eg, 42+8 = 50, will be treated as malpractice.